SLOTTED OPTICAL SWITCHES
PHOTOTRANSISTOR OUTPUT
KT 860/870/880/890 SERIES

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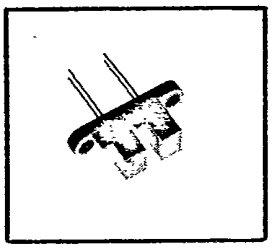
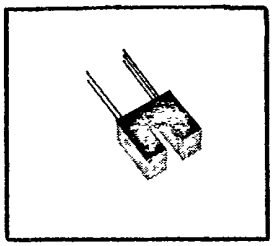
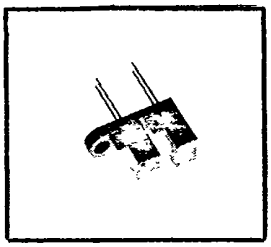


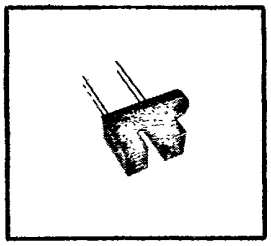
PACKAGE T



PACKAGE N



PACKAGE L



PACKAGE P

DESCRIPTION

The KT860/KT870 series of slotted optical switches provides the design engineer with the flexibility of a custom device from a standard product line. Building from a standard housing of .125" wide slot, the user can specify (1) Electrical output parameters, (2) Mounting tab configuration, (3) Lead spacing, (4) Discrete shell, and (5) Aperture widths.

All housings are an opaque grade of injection-molded polysulfone (P1700-935) to minimize the assembly's sensitivity to ambient radiation, both visible and near-infrared. Discrete shells (exposed only on the parallel faces inside the device throat) are either IR transmissive polysulfone (P1700-1615) for applications where aperture contamination may occur, or opaque polysulfone where maximum protection against ambient radiation is a concern.

PART NUMBER GUIDE

K T 8 X X X X X

- K T — Optek Assembly
- 8 — Phototransistor Output Family
- X — Discrete Shell Material Designation
  - 6 = IR Transmissive Polysulfone Discrete Shells With .02" Sq. Leads
  - 7 = Opaque Polysulfone Discrete Shells With .02" Sq. Leads
- X — Mechanical & Electrical Specification Variations
  - 0 = Electrical Parameter A, Lead Spacing .320"
  - 1 = Electrical Parameter B, Lead Spacing .320"
  - 2 = Electrical Parameter C, Lead Spacing .320"
  - 5 = Electrical Parameter A, Lead Spacing .220"
  - 6 = Electrical Parameter B, Lead Spacing .220"
  - 7 = Electrical Parameter C, Lead Spacing .220"
- X — Mounting Configurations
  - T = Both Mounting Tabs
  - N = No Mounting Tabs
  - L = Single Mounting Tab Emitter Side
  - P = Single Mounting Tab Sensor Side
- X — Aperture Width In Front Of Sensor
  - 5 = .050" 1 = .010"
- X — Aperture Width in Front of Emitter
  - 5 = .050" 1 = .010" *

EXAMPLE

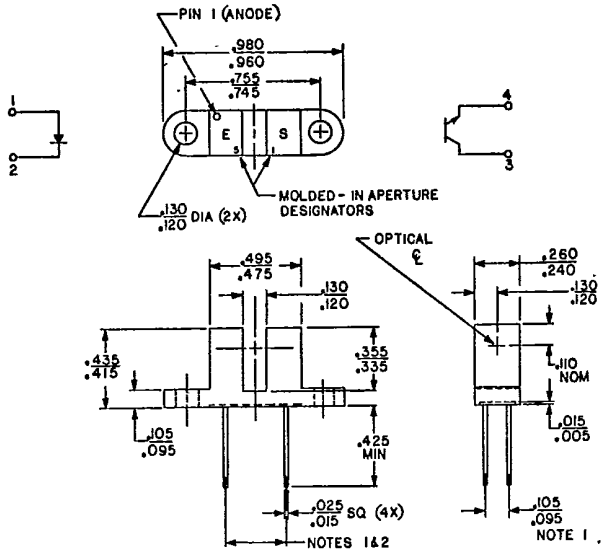
K T 8 7 0 N 5 1

- K T — Optek Assembly
- 8 — Phototransistor Output
- 7 — Opaque Polysulfone Discrete Shell With .02" Sq. Leads
- 0 — Electrical Parameter A .320" Lead Spacing
- N — No Tabs
- 5 — .050" Aperture in Front of Emitter
- 1 — .010" Aperture in Front of Sensor

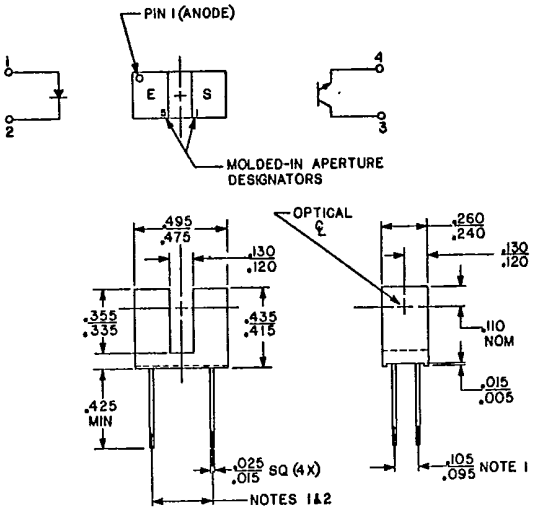
* Assemblies with dual .010" apertures are currently available with electrical parameter "A" only.

REVISED NOVEMBER 1986

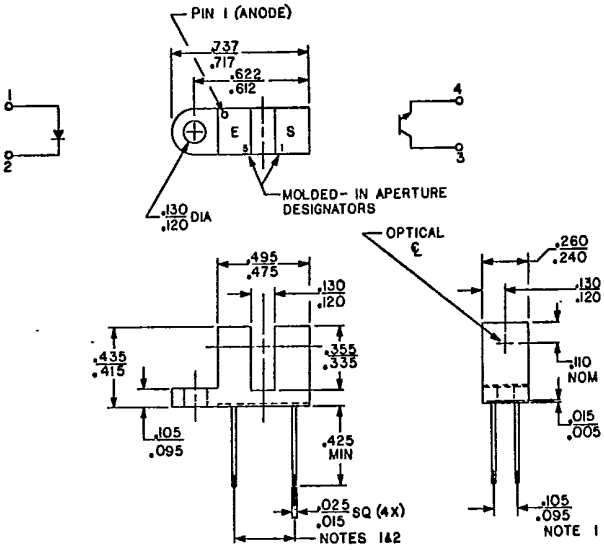
PACKAGE T



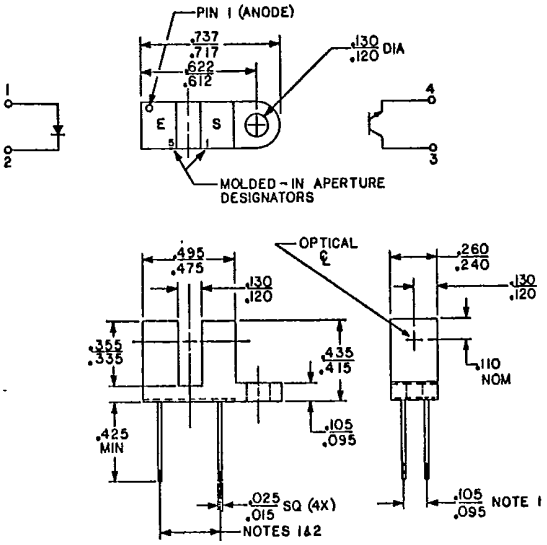
PACKAGE N



PACKAGE L



PACKAGE P



NOTES:
1. Dimension controlled at housing surface only.
2. KT860 thru KT862 and KT870 thru KT872 lead spacing: .320" ± .005"
   KT865 thru KT867 and KT875 thru KT877 lead spacing: .220" ± .005"
3. Housing is soluble in chlorinated hydrocarbons and ketones. Methanol and isopropanol are recommended as cleaning agents.

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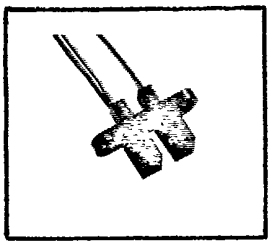
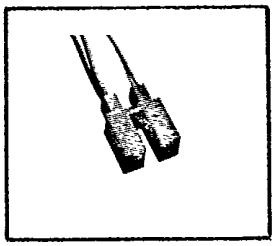
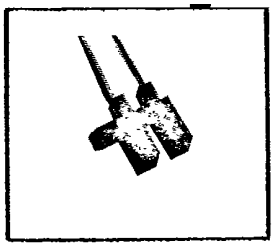


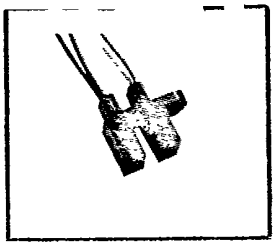
PACKAGE T



PACKAGE N



PACKAGE L



PACKAGE P

DESCRIPTION

The KT880/KT890 series of slotted optical switches provides the design engineer with the flexibility of a custom device from a standard product line. Building from a standard housing of .125" wide slot, the user can specify (1) Electrical output parameters, (2) Mounting tab configuration, (3) Discrete shell, and (4) Aperture widths.

All housings are an opaque grade of injection-molded polysulfone (P1700-935) to minimize the assembly's sensitivity to ambient radiation, both visible and near-infrared. Discrete shells (exposed only on the parallel faces inside the device throat) are either IR transmissive polysulfone (P1700-1615) for applications where aperture contamination may occur, or opaque polysulfone where maximum protection against ambient radiation is a concern.

Each terminal of the devices in this series is terminated with 24 inches of 7 strand 26 AWG, UL 1429 insulated wire. Insulation colors and functions are:

Red - IRED Anode	White - PHOTOTRANSISTOR Collector
Black - IRED Cathode	Green - PHOTOTRANSISTOR Emitter

Other wire lengths and/or colors are available. See your local representative or call the factory.

PART NUMBER GUIDE

K T 8 X X X X X

- K T — Optek Assembly
- 8 — Phototransistor Output Family
- 9 — Phototransistor Output Family
- 8 / 9 — Discrete Shell Material Designation
  - 8 = IR Transmissive Polysulfone Discrete Shells With 26 AWG UL1429 Wires, 24" Long
  - 9 = Opaque Polysulfone Discrete Shells With 26 AWG UL1429 Wires, 24" Long
- X — Mechanical & Electrical Specification Variations
  - 0 = Electrical Parameter A
  - 1 = Electrical Parameter B
  - 2 = Electrical Parameter C
- X — Mounting Configurations
  - T = Both Mounting Tabs
  - N = No Mounting Tabs
  - L = Single Mounting Tab Emitter Side
  - P = Single Mounting Tab Sensor Side
- X — Aperture Width In Front Of Sensor
- X — Aperture Width in Front of Emitter
  - 5 = .050" 1 = .010" *

EXAMPLE

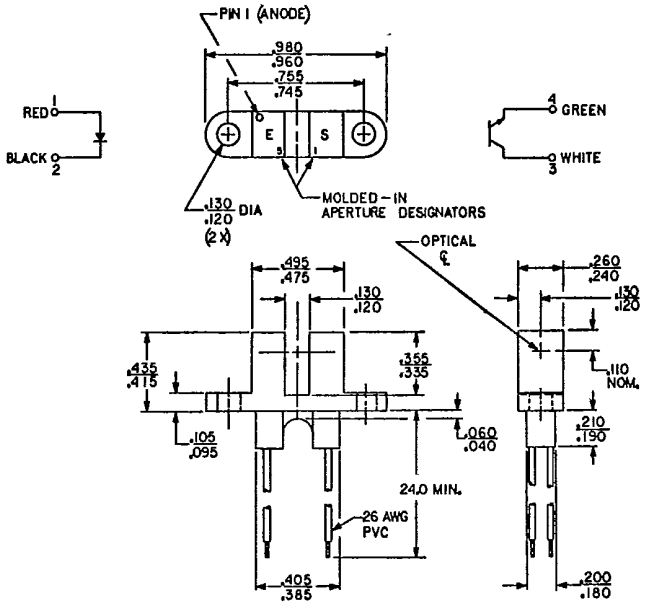
K T 8 9 0 N 5 1

- K T — Optek Assembly
- 8 9 — Phototransistor Output
- 8 9 — Opaque Polysulfone Discrete Shell With 26 AWG UL1429 Wires, 24" Long
- 0 — Electrical Parameter A
- N — No Tabs
- 5 — .050" Aperture in Front of Emitter
- 1 — .010" Aperture in Front of Sensor

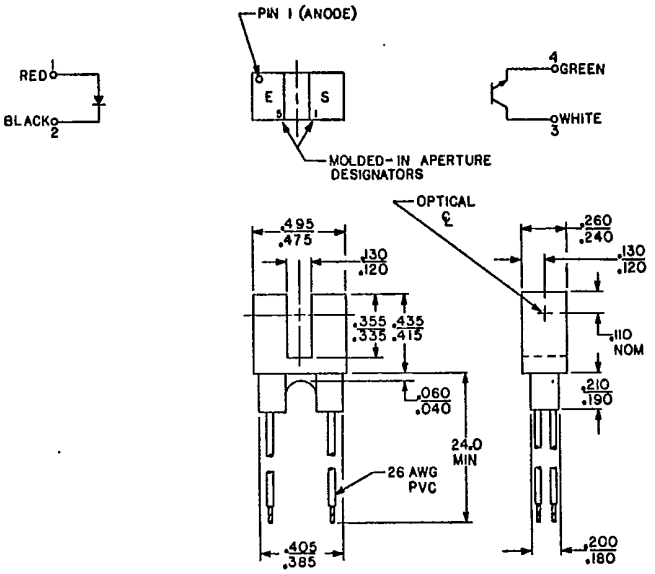
* Assemblies with dual .010" apertures are currently available with electrical parameter "A" only

PACKAGE CONFIGURATION

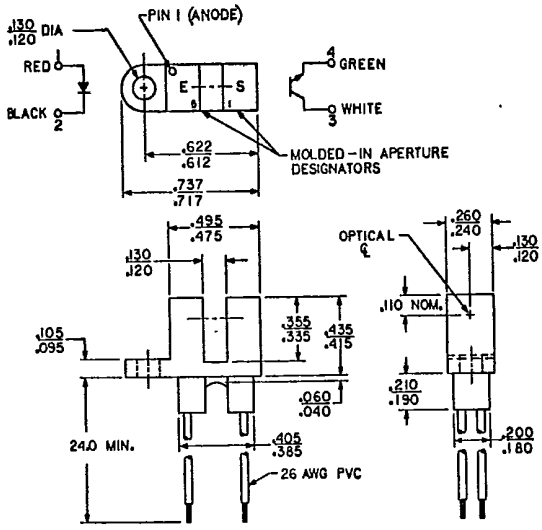
PACKAGE T



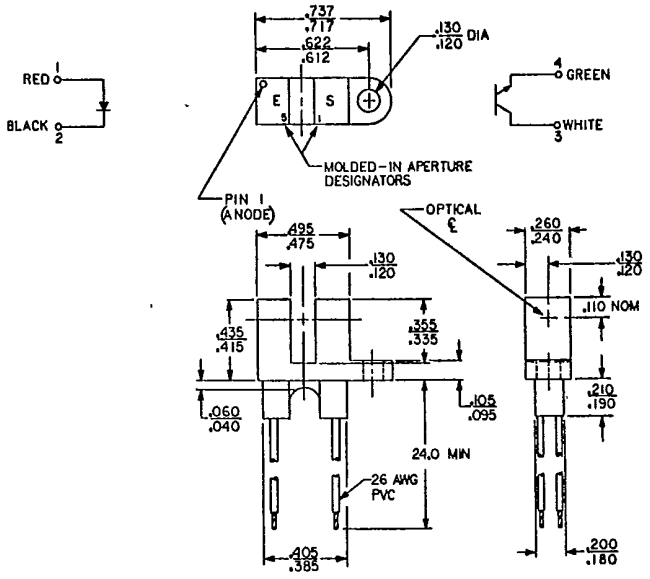
PACKAGE N



PACKAGE L



PACKAGE P



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TYPES KT860/KT870/KT880/KT890 SERIES

ELECTRICAL CHARACTERISTICS (25°C UNLESS OTHERWISE NOTED)

SYMBOL	PARAMETER	MIN	MAX	UNITS	TEST CONDITIONS
INPUT DIODE					
V_F	Forward Voltage		1.7	V	$I_F = 20$ mA
I_R	Reverse Current		100	μA	$V_R = 3$ V
OUTPUT PHOTOTRANSISTOR					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30		V	$I_C = 1$ mA
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5		V	$I_E = 100$ μA
I_{CEO}	Collector-Emitter Dark Current		100	nA	$V_{CE} = 10$ V
COUPLED					
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage Parameter A-KT860, KT865, KT870, KT875, KT880, KT890		0.4	V	$I_C = 400\mu A, I_F = 20$ mA
	Parameter B-KT861, KT866, KT871, KT876, KT881, KT891		0.4	V	$I_C = 800\mu A, I_F = 10$ mA
	Parameter C-KT862, KT867, KT872, KT877, KT882, KT892		0.6	V	$I_C = 1800\mu A, I_F = 20$ mA
$I_{C(ON)}$	On-State Collector Current Parameter A-KT860, KT865, KT870, KT875, KT880, KT890	500		μA	$V_{CE} = 10V, I_F = 20$mA
	Parameter B-KT861, KT866, KT871, KT876, KT881, KT891	1000		μA	$V_{CE} = 5V, I_F = 10$ mA
	Parameter C-KT862, KT867, KT872, KT877, KT882, KT892	1800		μA	$V_{CE} = 0.6V, I_F = 20$mA

ABSOLUTE MAXIMUM RATINGS (25°C unless otherwise noted)

Storage and Operating Temperature Range..... KT860/KT870 Series -40°C to +85°C (A)
KT880/KT890 Series -40°C to + 80°C (B)

Lead Soldering Temperature (1/16 inch from case for 5 sec. with soldering iron) .....+240°C (C)

INPUT DIODE

Forward DC Current.....50 mA
Peak Forward Current (1 μs pulse width, 300pps).....3 A
Reverse DC Voltage.....3 V
Power Dissipation.....100 mW (A) (B)

OUTPUT PHOTOTRANSISTOR

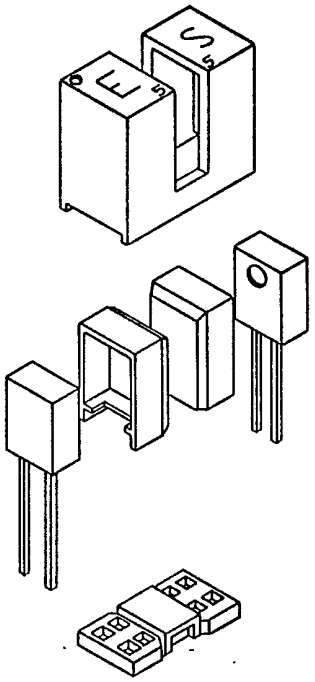
Collector-Emitter Voltage .....30 V
Emitter-Collector Voltage.....5 V
Collector DC Current.....30 mA
Power Dissipation.....100 mW (A) (B)

NOTES: (A) Derate linearly 1.67mW/°C above 25°C

(B) Derate linearly 1.82mW/°C above 25°C (Maximum storage and operating temperature limited by temperature rating of lead wires)

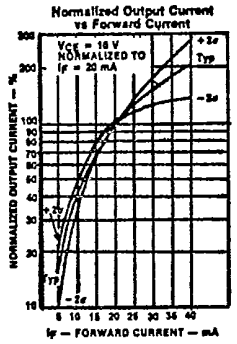
(C) Applies to KT860/KT870 Series only. RMA flux is recommended. Duration can be extended to 10 sec. max. when wave soldering.

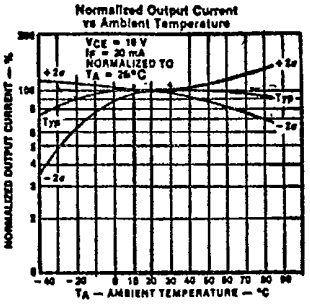
(D) All parameters tested using pulse technique.

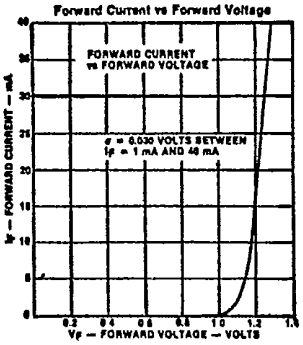


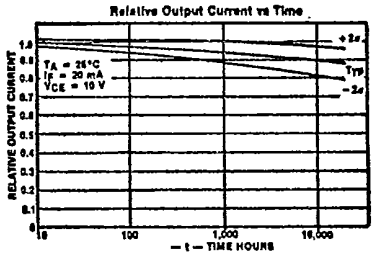
All housings are an opaque grade of injection-molded polysulfone (P1700-935) to minimize the assembly's sensitivity to ambient radiation, both visible and near-infrared. Discrete shells (exposed only on the parallel faces inside the device throat) are either IR transmissive polysulfone (P1700-1615) for applications where aperture contamination may occur, or opaque polysulfone (P1700-935) with aperture openings, where maximum protection against ambient radiation is a concern.

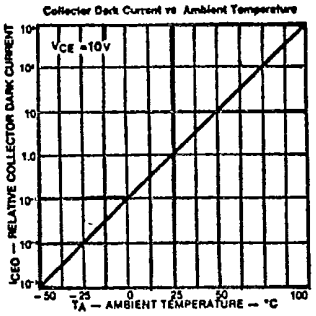
TYPICAL PERFORMANCE CURVES

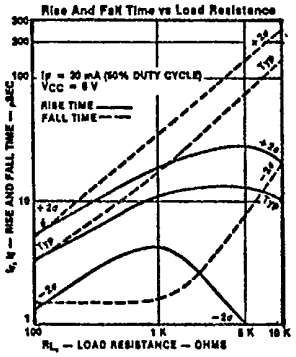


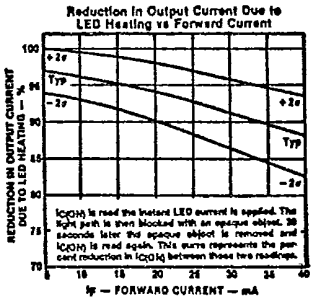




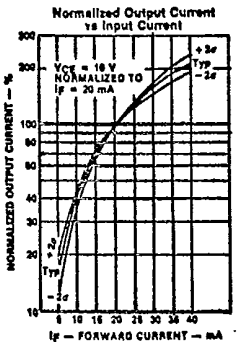


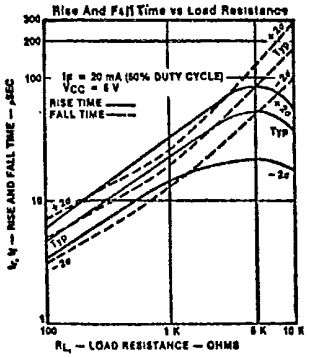






All Part Numbers Ending In "1"





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